

## **GENERAL DESCRIPTION**

OB2578T is an excellent primary side regulation power switch with CC/CV operation for medium level power AC/DC charger and adapter applications. The device operates in CCM/QR mode to provide high efficiency along with several functions of built-in protections. It removes the need for secondary feedback circuitry to lower the total bill of material cost. Proprietary Constant Voltage (CV) and Constant Current (CC) control is integrated as shown in the figure below.

In CV control, the controller changes the mode of operation according to line voltage and load condition. At full loading, the controller operates in fixed frequency CCM in low line voltage and quasi-resonant (QR) mode in high line voltage. The primary side regulation power supplies up to high power without the efficiency limitation of DCM or audible noise.

In CC control, OB2578T samples the primary-side average current and the demagnetization pulse to regulation the output current. The current and output power setting can be adjusted externally by the sense resistor Rs at CS pin.

OB2578T offers comprehensive protection coverage with auto-recovery feature including Cycle-by-Cycle current limiting, VDD OVP, OLP, SCP, OTP etc.

OB2578T consumes less than 75mW input power at no-load condition with high line voltage.
OB2578T is offered in SOP8 and DIP8 package.

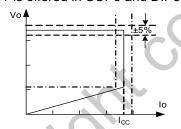


Figure 1. Typical CC/CV Curve

#### **FEATURES**

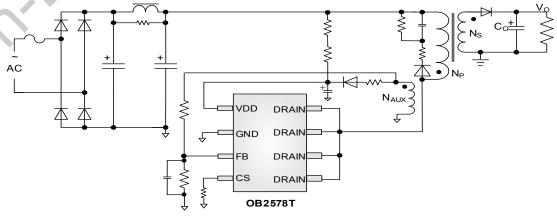
- Primary-side sensing and regulation operates in CCM/QR mode without TL431 and opto-coupler
- High precision constant voltage and current regulation at universal AC input
- Fixed frequency (65kHz) CCM mode operation with low line voltage at full load
- Integrated 4A MOSFET
- Quasi-resonant operation for high efficiency in high line voltage
- Programmable CV and CC regulation
- Good dynamic response
- Built-in line compensation for tight CC regulation
- Built-in fixed cable compensation
- Built-in primary winding inductance compensation
- Built-in control loop compensation
- Built-in leading edge blanking (LEB)
- Ultra low start-up current and low operating current
- Comprehensive protection coverage with auto-recovery
  - VDD over voltage protection (VDD OVP)
  - VDD under voltage lockout with hysteresis (UVLO)
  - Cycle-by-cycle current limiting
  - Feedback open loop protection (OLP)
  - Output short circuit protection (SCP)

## **APPLICATIONS**

Medium level Power AC/DC offline SMPS for

- Cell phone charger
- Tablet PC
- AC/DC adapter
- Set-top box power supplies

## **TYPICAL APPLICATION**

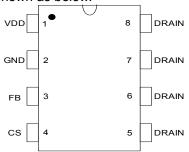




## **GENERAL INFORMATION**

## **Pin Configuration**

The OB2578T is offered in SOP8 and DIP8 package, shown as below.



**Ordering Information** 

Part Number	Description
OB2578TCP	SOP8, Halogen-free in Tube
OB2578TCPA	SOP8, Halogen-free in T&R
OB2578TAP	DIP8, Halogen-free in Tube

**Package Dissipation Rating** 

Package	RθJA (°C/W)	RθJC (°C/W)			
SOP-8	85	25			
DIP8	70	17			

**Absolute Maximum Ratings** 

Absolute Maximum Ratings		
Parameter	Value	
Drain Voltage (off state)	-0.3V to Bvdss	
VDD Voltage	-0.3 to 35V	
FB Input Voltage	-0.3 to 7V	
CS Input Voltage	-0.3 to 7V	
Min/Max Operating Junction Temperature T <sub>J</sub>	-40 to 150 ℃	
Operating Ambient Temperature T <sub>A</sub>	-20 to 85 ℃	
Min/Max Storage Temperature T <sub>stq</sub>	-55 to 150 ℃	
Lead Temperature (Soldering, 10secs)	260 ℃	

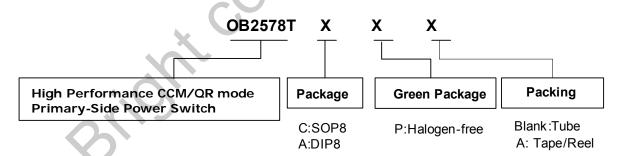
**Note:** Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

## **Output Power Table**

Product	90Vac~264Vac Input		
OB2578TCP	20W		
OB2578TAP	24W		

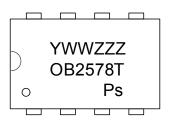
**Recommended Operating Condition** 

Symbol	Parameter	Range
VDD	VDD Supply Voltage	9 to 29V





# **Marking Information**



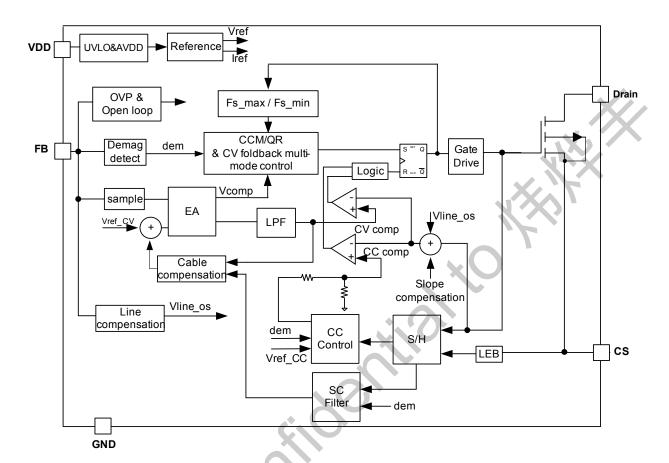
Y:Year Code WW:Week Code(01-52) ZZZ:Lot Code P:Halogen-free Package S:Internal Code(Optional)

## **TERMINAL ASSIGNMENTS**

Pin Num	Pin Name	I/O	Description
1	VDD	Р	Power Supply
2	GND	Р	Ground
3	FB	I	The voltage feedback from auxiliary winding. Connected to resistor divider from auxiliary winding reflecting output voltage.
4	CS	ı	Current sense input. Connect a sense resistor from this pin to ground.
5~8	DRAIN	I	Drain of power MOS. Connected to input line voltage



## **BLOCK DIAGRAM**





# **ELECTRICAL CHARACTERISTICS**

(TA = 25°C, VDD=18V, if not otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit	
Supply Voltage (VDD) Section							
I start-up	Start up current	VDD=UVLO_OFF-1V		5	15	ųΑ	
I standy	Standby current			0.8	1.0	mA	
lop_s	Operating current	FB=1V, GATE pin floating		1.5	2.5	mA	
UVLO(OFF)	VDD under voltage lockout exit		14.5	16	17.5	V	
UVLO(ON)	VDD under voltage lockout enter		6.5	7	7.5	٧	
VDD_OVP	VDD over voltage protection		31	33	35	V	
Current Sense Inpu	it Section				•		
TLEB+TD_OC	LEB time and OCP propagation			520		ns	
Vth_ocp_max	Maximum over current threshold			650		mV	
FB Input Section					•		
Vref_fb	Reference voltage for feedback threshold		2.475	2.5	2.525	V	
V_OVP	Output Over voltage threshold			3.25		V	
Vth_cc_shutdown	CC mode shut down threshold			1.55		٧	
Tdbs_cc_shutdown	CC mode shut down debounce time	2	55	60	65	ms	
	Maximum cable compensation to Vout ratio@lfb > 1.02mA	(Naux/Np) /Rup		2			
∆cable_max/Vout	Maximum cable compensation to Vout ratio@lfb<1.0mA	Recommended value Vac=165Vac @Ifb=1.0mA		4		%	
CC Loop Section							
Vref_cc	CC loop reference		190	200	210	mV	
Timer Section	7				•		
Fs_ccm	CV CCM fix frequency		60	65	70	kHz	
Fmin	Minimum switch frequency		0.27	0.3	0.33	kHz	
Internal OTP Section	on						
OTP_int_enter	internal OTP enter temperature			150		$^{\circ}$	
OTP_int_exit	internal OTP exit temperature			120		$^{\circ}$ C	
MOSFET Section							
Vds_max <sup>Note</sup>	Mosfet drain-source spike voltage capability		650			V	
Rdson	Static drain to source on resistance			2.2		Ω	

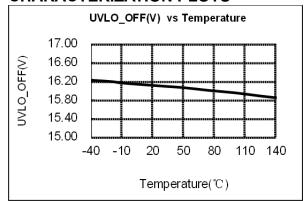
Note: MOSFET minimum drain to source breakdown voltage is 620V, Voltage spike at not higher than 650V is allowed under the condition that

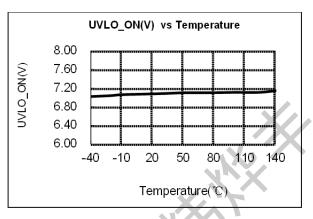
Voltage spike duty cycle does NOT exceed 3% A) B)

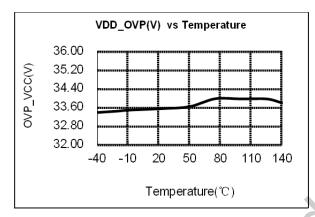
Voltage spike pulse width does NOT exceed 200ns.

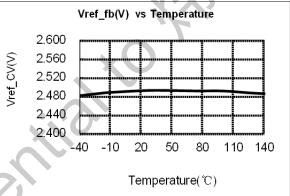


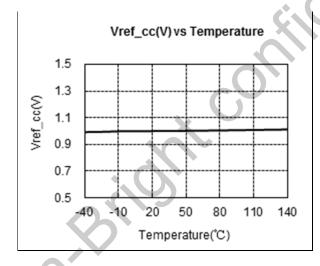
## **CHARACTERIZATION PLOTS**













## **OPERATION DESCRIPTION**

OB2578T is an excellent integrated multi-mode (see Figure 2) PWM controller optimized for off-line middle power AC/DC applications. It operates in continuous conduction mode (CCM) and quasi-resonant mode (QR) to provide high efficiency with primary side sensing and regulation thus provides cost effective solution for energy efficient power supplies.

At full loading, the IC operates in fixed frequency (65KHz) CCM mode in the low line input voltage and it operates in QR mode in high line input voltage. In this way, high efficiency in the universal input range at full loading can be achieved.

At normal load condition, it operates in QR mode. To minimize switching loss, the maximum switching frequency in QR mode is internally limited to 80 kHz (typical). When the load goes low, it operates in PFM mode with valley switching for high power conversion efficiency. When the load is very small, the IC switch frequency can be reduced to 0.3kHz to minimize the standby power loss. As a result, high conversion efficiency can be achieved in the whole loading range.

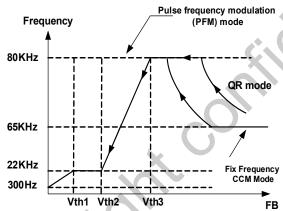


Figure 2 Multi-mode operation diagram Proprietary built-in CV and CC control can achieve high precision CC/CV control meeting most charger application requirements.

#### Startup Current and Start Up Control

Startup current of OB2578T is designed to be very low so that VDD could be charged up above UVLO threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet achieve a reliable startup in application.

## **Operating Current**

The Operating current of OB2578T is as low as around 800uA @ no load mode. Good efficiency and less than 75mW standby power is achieved with the low operating current.

#### **CV Mode Operation**

OB2578T is designed to produce good CC/CV control characteristic as shown in the Figure. 1. In charger applications, a discharged battery charging starts in the CC portion of the curve until it is nearly full charged and smoothly switches to operate in CV portion of the curve. The CC portion provides output current limiting. In CV operation, the output voltage is regulated through the primary side control. In CC operation mode, OB2578T will regulate the output current constant regardless of the output voltage drop.

## **Principle of Operation**

With OB2578T proprietary CC/CV control, system can be designed in CCM/DCM mode for flyback system (Refer to the Typical Application Diagram in page1).

In the flyback converter, the output voltage can be sensed via the auxiliary winding. During MOSFET turn-on time, the load current is supplied from the output filter capacitor and the current in the primary winding ramps up. When MOSFET turns off, the energy stored in the primary winding is transferred to the secondary side and the current in the secondary winding is

$$I_S = \frac{N_P}{N_S} \cdot I_P \tag{1}$$

The auxiliary winding voltage reflects the output voltage as shown in Figure.3 and it is given by

$$V_{AUX} = \frac{N_{AUX}}{N_{s}} \cdot (V_O + \Delta V)$$
 (2)

Where  $\Delta \text{V}$  indicates the voltage drop of the output Diode.

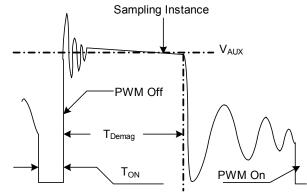


Figure.3. Auxiliary winding voltage waveform Via a resistor divider connected between the auxiliary winding and FB PIN, the auxiliary voltage is sampled and hold during the demagnetization cycle. The sampling instance is variable according to the demagnetization width. The output voltage can be monitored when the secondary current is



small. Thus  $\Delta V$  can be ignored. The sampled voltage is compared with reference voltage Vref\_fb (typical 2.5V) and the difference is amplified. The error amplifier output reflects the load condition and controls the switching off time to regulate the output voltage, thus constant output voltage can be achieved.

## **CC Mode Operation**

OB2578T samples the average CS and the transformer core demagnetization period to regulate the output current. The primary average CS is adaptively controlled according to vref\_cc and the internal CC comp voltage.

$$Io = N_{ps} * \frac{vref\_cc}{Rs}$$
 (3)

Where  $Vref\_cc$  (typical 0.2V) is the reference voltage of CC Loop,  $N_{ps}$  is the turn ratio of primary side to secondary side of the transformer. Rs is the value of the sense resistor.

Refer to the equation 3, regulating the vref\_cc can achieve the constant output current. The constant output current is independent of the primary winding inductance.

## **Adjustable CC Point and Output Power**

In OB2578T, the CC point and maximum output power can be externally adjusted by external current sense resistor Rs at CS pin as illustrated in the typical application diagram. The larger the Rs is, the smaller CC point is, and the smaller output power becomes, and vice versa as shown in Figure.4.

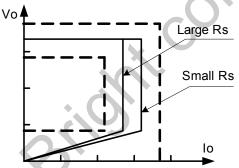


Figure.4. Adjustable output power by changing Rs

#### **CC Line Voltage Compensation**

The variation of maximum output current in CC mode can be rather large at high input voltage (such as 264Vac) if no compensation is provided. The CC threshold value is self adjusted higher at higher AC voltage due to CC propagation delay. In OB2578T, the AC line voltage information is sampled through detecting FB sourcing current when gate turns on, and the AC line voltage information is added to the CS pin voltage. So the maximum CS threshold voltage Vcs\_max in OB2578T is a function of the CC threshold and AC line voltage information as shown in Figure 5.

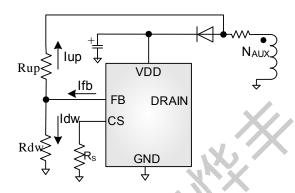


Figure.5. CC line voltage compensation

The CS threshold voltage Vcs is given by

$$Vcs = Vth \ cc - \frac{1}{M} \cdot \frac{Naux}{Np} \cdot \sqrt{2} \cdot Vac \cdot \frac{Ros}{Rup}$$
 (5)

Where Vth\_cc a threshold determined by internal CC comp voltage, M is the FB current mirror ratio (M=430), Naux/Np is the auxiliary winding to primary winding turns ratio, Vac is the effective voltage of input voltage, Ros is the internal line compensation offset resistor (Ros=1.5kohm), Rup is the external FB PIN upside resistor.

#### Current Sensing and Leading Edge Blanking

Cycle-by-Cycle current limiting is offered in OB2578T. The switch current is detected by a sense resistor connected to the CS pin. An internal leading edge blanking circuit chops off the sensed voltage spike at initial power MOSFET on state so that the external RC filtering on sense input is no longer needed.

# Internal Over-Temperature Protection with GATE Shutdown

The internal OTP circuit of OB2578T is triggered and only shuts down the internal MOSFET when the chip temperature rises above  $150^{\circ}$ C, and the internal MOSFET will resume switching after the chip temperature falls below  $120^{\circ}$ C.

### **Protection Control**

Good power supply system reliability is achieved with its rich protection features including Cycle-by-Cycle current limiting, Output over voltage protection, VDD over voltage protection, short circuit protection, Under Voltage Lockout on VDD.

VDD is supplied by transformer auxiliary winding output after startup. The output of OB2578T is shut down when VDD drops below UVLO (ON) and the power converter enters power on start-up sequence thereafter.

## **CC** mode shutdown function

In OB2578T, to prevent the controller operating



under abnormal conditions, the minimum output voltage of CC mode is limited to predetermined voltage. The CC output voltage is sampled through FB pin from auxiliary winding at the middle of the de-magnetization. When the FB sampled voltage is below 1.55V and last 60ms, the controller will shut down.

### **PCB Layout Consideration**

The following rules should be followed in OB2578T PCB Layout:

The Area of Power Loop: The area of the main current loop should be as small as possible to reduce EMI radiation, such as the primary current loop, the snubber circuit and the secondary rectifying loop (Red wire as shows in Fig.6). Bypass Capacitor and FB Divider Resistor: The bypass capacitor on VDD and the FB divider resistor should be placed as close as possible to pin out. And the negative node of VDD capacitor and the FB down resistor should be connected directly to the IC GND pin before single point connected to the negative node of the output capacitor. (Blue wire as shows in Fig.6)

Ground Path: The GND path of the input power loop and IC controller path should be separated and connected at the negative terminal of input capacitor by single point, such as power sense resistor, the negative of the auxiliary winding and the IC GND.

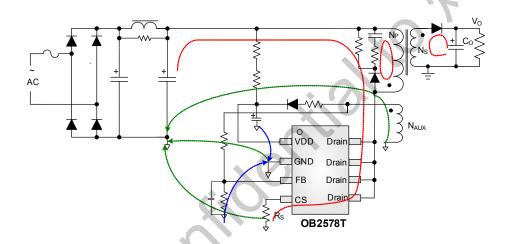


Fig.6 Fly-back Schematic with OB2578T

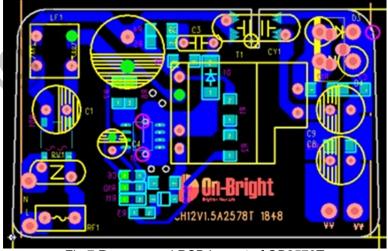
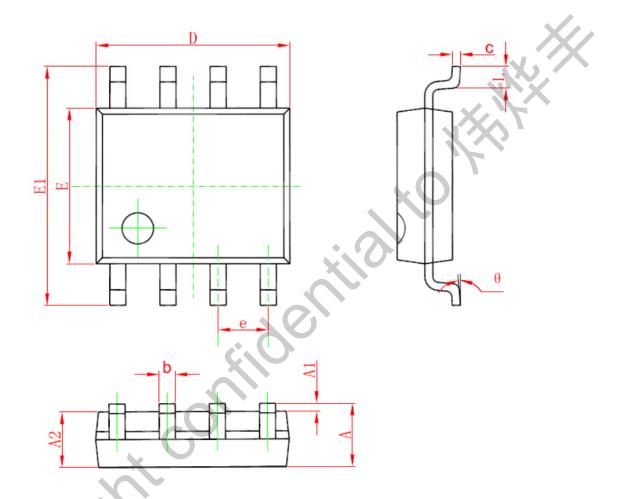


Fig.7 Recommend PCB Layout of OB2578T



# **PACKAGE MECHANICAL DATA**

# SOP8 PACKAGE OUTLINE DIMENSIONS

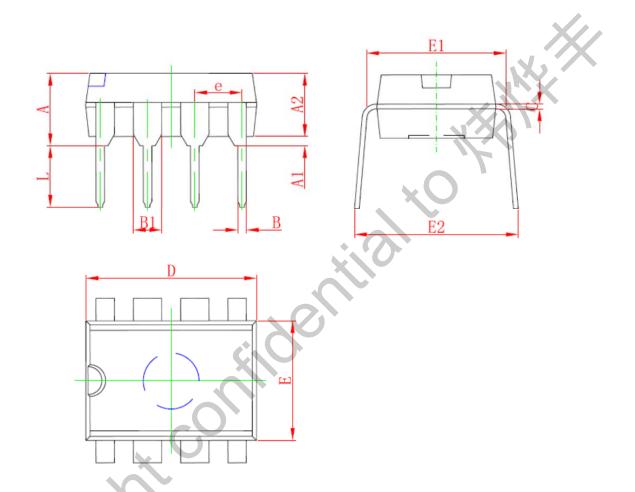


Symbol	Dimensions In Millimeters		Dimensions In Inches		
Syllibol	Min	Max	Min	Max	
A	1.350	1.750	0.053	0.069	
A1	0.050	0.250	0.002	0.010	
A2	1.250	1.650	0.049	0.065	
b	0.310	0.510	0.012	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.150	0.185	0.203	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270 (BSC)		0.05 (BSC)		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



## PACKAGE MECHANICAL DATA

## **DIP8 PACKAGE OUTLINE DIMENSIONS**



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	3.710	5.334	0.146	0.210	
A1	0.381		0.015		
A2	2.921	4.953	0.115	0.195	
В	0.350	0.650	0.014	0.026	
B1	1.524 (BSC)		0.06 (BSC)		
С	0.200	0.360	0.008	0.014	
Ď	9.000	10.160	0.354	0.400	
E	6.096	7.112	0.240	0.280	
E1	7.320	8.255	0.288	0.325	
е	2.540 (BSC)		0.1 (BSC)		
L	2.921	3.810	0.115	0.150	
E2	7.620	10.920	0.300	0.430	



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